

U.S. PATENT DOCUMENTS

*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Name	Classification
*	Α	US-2004/0124476	07-2004	Miyano, Kiyotaka	257/371
*	В	US-6,696,348	02-2004	Xiang, Qi	438/424
*	С	US-2004/0212035	10-2004	Yeo et al.	257/510
*	D	US-5,879,996	03-1999	Forbes, Leonard	438/289
*	Ε	US-2005/0093104	05-2005	leong et al.	257/627
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*	н	US-6,982,229	01-2006	Suvkhanov et al.	438/752
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NON-PATENT DOCUMENTS

*		Include as applicable: Author, Title Date, Publisher, Edition or Volume, Pertinent Pages)
	U	Randa, "A Novel Elevated Source/Drain PMosfet formed by Ge-B/Si Intermixing",2002 IEEE
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*A copy of this reference is not being furnished with this Office action. (See MPEP § 707.05(a).)

Dates in MM-YYYY format are publication dates. Classifications may be US or foreign.